

Octal Buffer/Line Driver with 3-STATE Outputs

74VHCT244A

General Description

The VHCT244A is an advanced high speed CMOS octal bus transceiver fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHCT244A is a noninverting 3-STATE buffer having two active-LOW output enables. This device is designed to be used as 3-STATE memory address drivers, clock drivers, and bus oriented transmitter/receivers.

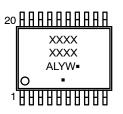
Protection circuits ensure that 0~V to 5.5~V can be applied to the input and output (*) pins without regard to the supply voltage. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 5~V to 3~V systems and two supply systems such as battery back up. *Outputs in OFF-State.

Features

- High Speed: t_{PD} 5.9 ns (typ) at $V_{CC} = 5 \text{ V}$
- Power Down Protection is Provided on Inputs and Outputs
- Low Power Dissipation: $I_{CC} = 4 \mu A \text{ (max)} @ T_A = 25 \text{ °C}$
- Pin and Function Compatible with 74HCT244
- This is a Pb-Free Device



MARKING DIAGRAMS

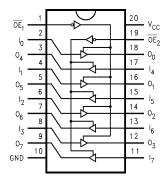


TSSOP-20

XXXXXX = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
= Pb-Free Package

(Note: Microdot may be in either location)

CONNECTION DIAGRAM



PIN DESCRIPTION

Pin Names	Description
\overline{OE}_1 , \overline{OE}_2	3-STATE Output Enable Inputs
I ₀ -I ₇	Inputs
O ₀ -O ₇	3-STATE Outputs

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

74VHCT244A

LOGIC SYMBOL

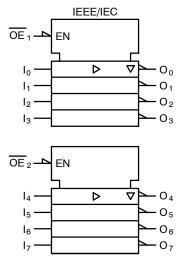


Figure 1. Logic Symbol

TRUTH TABLES

Inp	uts	Outputs
ŌE ₁	I _n	(Pins 12, 14, 16, 18)
L	L	L
L	Н	Н
Н	X	Z

Inp	uts	Outputs
ŌĒ ₂ I _n		(Pins 3, 5, 7, 9)
L	L	L
L	Н	Н
Н	Х	Z

NOTE: H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = High Impedance

MAXIMUM RATINGS

Symbol	Pa	Value	Unit	
V _{CC}	DC Supply Voltage		-0.5 to +6.5	V
V _{IN}	DC Input Voltage		-0.5 to +6.5	V
V _{OUT}	DC Output Voltage	Active Mode (High or Low State)	-0.5 to V _{CC} + 0.5	V
		Tristate Mode (Note 1)	-0.5 to +6.5	1
		Power-Off Mode (V _{CC} = 0 V)	-0.5 to +6.5	1
I _{IN}	DC Input Current, per Pin	±20	mA	
I _{OUT}	DC Output Current, per Pin	±25	mA	
I _{CC}	DC Supply Current, V _{CC} and GND Pir	±75	mA	
I _{IK}	Input Clamp Current	-20	mA	
I _{OK}	Output Clamp Current	-20	mA	
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case f	or 10 Seconds	260	°C
T_J	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)		150	°C/W
P_{D}	Power Dissipation in Still Air at 25 °C	833	mW	
MSL	Moisture Sensitivity	Level 1		
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.245 in	
V _{ESD}	ESD Withstand Voltage (Note 3) Human Body Model		2000	V
		Charged Device Model	N/A	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Applicable to devices with outputs that may be tri-stated.
- Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
 HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

Symbol	Para	Parameter			
V _{CC}	DC Supply Voltage	DC Supply Voltage			V
V _{IN}	DC Input Voltage (Note 4)			5.5	V
V _{OUT}	DC Output Voltage (Note 4) Active Mode (High or Low State)		0	V _{CC}	V
		Tristate Mode	0	5.5	1
		Power-Off Mode (V _{CC} = 0 V)	0	5.5	1
T _A	Operating Temperature	•	-40	+85	°C
t _r , t _f	Input Rise or Fall Rate	V _{CC} = 4.5 V to 5.5 V	0	20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS

						T _A = 25°C		T _A = -40°C	C to +85°C		
Symbol	Parameter	Con	ditions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit	
V _{IH}	HIGH Level Input			4.5	2.0	_	_	2.0	-	V	
	Voltage			5.5	2.0	-	_	2.0	-		
V_{IL}	LOW Level Input			4.5	-	_	0.8	_	0.8	V	
	Voltage			5.5	ı	-	0.8	-	0.8		
V _{OH}	HIGH Level	$V_{IN} = V_{IH}$	I _{OH} = -50 μA	4.5	4.40	4.50	_	4.40	-	V	
	Output Voltage	or V _{IL}	$I_{OH} = -8 \text{ mA}$		3.94	-	-	3.80	-		
V _{OL}	LOW Level	$V_{IN} = V_{IH}$	I _{OL} = 50 μA	4.5	-	0.0	0.1	-	0.1	V	
	Output Voltage	Output Voltage	or V _{IL}	$I_{OL} = 8 \text{ mA}$		-	_	0.36	_	0.44	
l _{OZ}	3-STATE Output Off-State Current	$V_{IN} = V_{IH} \alpha$ $V_{OUT} = V_{C}$		5.5	-	-	±0.25	-	±2.5	μΑ	
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V	or GND	0–5.5	-	-	±0.1	-	±1.0	μΑ	
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$	V _{IN} = V _{CC} or GND		-	-	4.0	-	40.0	μΑ	
I _{CCT}	Maximum I _{CC} / Input	V _{IN} = 3.4 V, Other Input = V _{CC} or GND		5.5	-	-	1.35	-	1.50	mA	
l _{OFF}	Output Leakage Current (Power Down State)	V _{OUT} = 5.5	V	0.0	-	-	0.5	-	5.0	μΑ	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NOISE CHARACTERISTICS

				T _A = 25 °C		
Symbol	Parameter	Conditions	V _{CC} (V)	Тур	Limits	Unit
V _{OLP} (Note 5)	Quiet Output Maximum Dynamic V _{OL}	C _L = 50 pF	5.0	0.9	1.1	V
V _{OLV} (Note 5)	Quiet Output Minimum Dynamic V _{OL}	C _L = 50 pF	5.0	-0.9	-1.1	V
V _{IHD} (Note 5)	Minimum HIGH Level Dynamic Input Voltage	C _L = 50 pF	5.0	-	2.0	V
V _{ILD} (Note 5)	Maximum LOW Level Dynamic Input Voltage	C _L = 50 pF	5.0	-	0.8	V

^{5.} Parameter guaranteed by design.

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AC ELECTRICAL CHARACTERISTICS

						T _A = 25 °C		T _A = -40 °C	C to +85 °C	
Symbol	Parameter	Cond	litions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
t _{PLH} ,	Propagation		C _L = 15 pF	5.0 ±0.5	-	5.4	7.4	1.0	8.5	ns
t _{PHL}	Delay Time		C _L = 50 pF]	-	5.9	8.4	1.0	9.5	
t _{PZL} ,	3-STATE Output	$R_L = 1 \text{ k}\Omega$	C _L = 15 pF	5.0 ±0.5	-	7.7	10.4	1.0	12.5	ns
^t PZH	Enable Time		C _L = 50 pF]	-	8.2	11.4	1.0	13.5	
t _{PLZ} , t _{PHZ}	3-STATE Output Disable Time	R _L = 1 kΩ	C _L = 50 pF	5.0 ±0.5	-	8.8	11.4	1.0	13.0	ns
t _{OSLH} , t _{OSHL}	Output to Output Skew	(Note 6)		5.0 ±0.5	-	-	1.0	_	1.0	ns
C _{IN}	Input Capacitance	V _{CC} = Ope	n		-	4	10	-	10	pF
C _{OUT}	Output Capacitance	V _{CC} = 5.0 \	/		-	9	-	-	-	pF
C _{PD}	Power Dissipation Capacitance	(Note 7)			_	18	_	_	_	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
74VHCT244AMTCX	VHCT 244A	TSSOP-20	2500 Units / Tape & Reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Parameter guaranteed by design. t_{OSLH} - |t_{PLHmax} - t_{PLHmin}|; t_{OSHL} - |t_{PLHmax} - t_{PLHmin}|
 C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (Opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: CPD (total) = 20 + 12n

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REVISION HISTORY

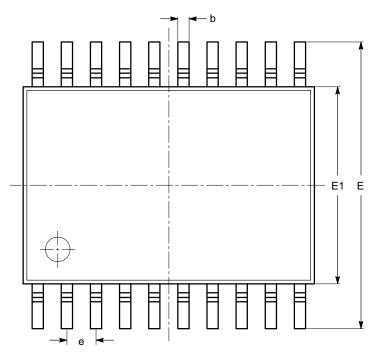
Revision	Description of Changes	Date
1	Converted the Data Sheet to onsem i format with the updates in Ordering Information Table, Recommended Operating Table, Maximum Rating Table.	9/16/2025

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.



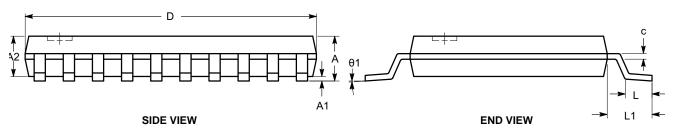
TSSOP20, 4.4x6.5 CASE 948AQ ISSUE A

DATE 19 MAR 2009



SYMBOL	MIN	NOM	MAX
А			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
С	0.09		0.20
D	6.40	6.50	6.60
Е	6.30	6.40	6.50
E1	4.30	4.40	4.50
е		0.65 BSC	
L	0.45	0.60	0.75
L1		1.00 REF	
θ	0°		8°

TOP VIEW



Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-153.

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DESCRIPTION:	TSSOP20, 4.4X6.5		PAGE 1 OF 1			

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